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<u>Vishay Semiconductor/Diodes Division</u> <u>VBT1045BP-M3/8W</u>

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VBT1045BP-M3/8W - DIODE SCHOTTKY 10A 45V TO-263AB

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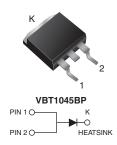
VBT1045BP-M3

Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.41 \text{ V}$ at $I_F = 5 \text{ A}$

TMBS® TO-263AB



PRIMARY CHARACTERISTCS			
Package	TO-263AB		
I _{F(DC)}	10 A		
V_{RRM}	45 V		
I _{FSM}	100 A		
V _F at I _F = 10 A	0.52 V		
T _{OP} max. (AC mode)	150 °C		
T _J max. (DC forward current)	200 °C		
Diode variation	Single die		

FEATURES





· Low forward voltage drop, low power losses

• High efficiency operation • Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C

· Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	VBT1045BP	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	45	V	
Maximum DC forward bypassing current (fig. 1)	I _{F(DC)} (1)	10	А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	100	А	
Operating junction temperature range (AC mode)	T _{OP}	- 40 to + 150	°C	
Junction temperature in DC forward current without reverse bias, $t \le 1\ h$	T _J ⁽²⁾	≤ 200	°C	

Notes

(2) Meets the requirements of IEC 61215 ed.2 bypass diode thermal test

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT
Instantaneous forward voltage $ \frac{I_F = 10}{I_F = 5} $	I _F = 5 A	T _A = 25 °C	- V _F ⁽¹⁾	0.50	-	V
	I _F = 10 A			0.57	0.68	
	I _F = 5 A	T _A = 125 °C		0.41	-	
	I _F = 10 A			0.52	0.64	
Reverse current	V 45 V	T _A = 25 °C	I _R ⁽²⁾	-	500	μA
	V _R = 45 V	T _A = 125 °C		5	15	mA

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

 $^{(2)}$ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	VBT1045BP	UNIT	
Typical thermal resistance	$R_{ hetaJC}$	3.0	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VBT1045BP-M3/4W	1.37	4W	50/tube	Tube	
TO-263AB	VBT1045BP-M3/8W	1.37	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

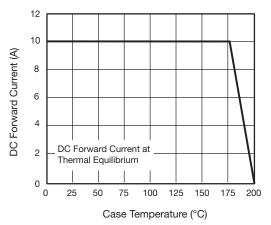


Fig. 1 - Maximum Forward Current Derating Curve

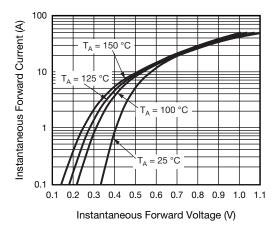


Fig. 2 - Typical Instantaneous Forward Characteristics

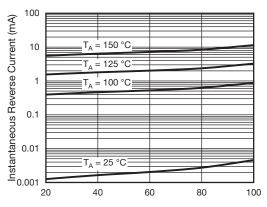


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Percent of Rated Peak Reverse Voltage (%) Fig. 3 - Typical Reverse Characteristics

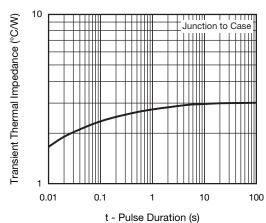


Fig. 5 - Typical Transient Thermal Impedance

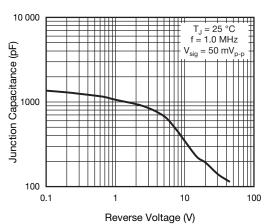
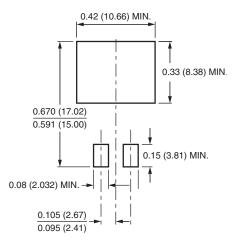


Fig. 4 - Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-263AB 0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.160 (4.06) 0.055 (1.40) 0.045 (1.14) 0.245 (6.22) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) 0.591 (15.00) Κ 2 0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

Mounting Pad Layout



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